# NSN 5962-01-218-8483

Memory Microcircuit - Page 1 of 1



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## **Body Length:**

Between 0.930 inches and 0.975 inches

### Body Width:

Between 0.245 inches and 0.300 inches

## **Body Height:**

0.150 inches

## **Operating Tempurature Range:**

+0.0/+70.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and schottky and 3-state output and programmable

#### **Inclosure Material:**

Ceramic and glass

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

10 input

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

#### **Time Rating Per Chacteristic:**

15.00 nanoseconds propagation delay time, low to high level output and 15.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

#### **Terminal Type And Quantity:**

20 printed circuit

## Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

Fiig:

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